

RECEIPT



ATTORNEY DOCKET NO. Q58705✓  
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Yoji OKAZAKI, et al. ✓

Appln. No.: 09/659,456 ✓

Group Art Unit: 2874✓

Filed: September 11, 2000 ✓

Examiner: NOT YET ASSIGNED

For: LASER APPARATUS IN WHICH GaN-BASED COMPOUND SURFACE-EMITTING SEMICONDUCTOR ELEMENT IS EXCITED WITH GaN-BASED COMPOUND SEMICONDUCTOR LASER ELEMENT

**REQUEST FOR CORRECTED OFFICIAL FILING RECEIPT**

Assistant Commissioner for Patents  
Office of Initial Patent Examination  
Customer Service Center  
Washington, D.C. 20231

Sir:

We enclose a copy of the Official Filing Receipt for the above-identified application and request the following correction:

**TITLE: LASER APPARATUS IN WHICH GaN-BASED COMPOUND SURFACE-EMITTING SEMICONDUCTOR ELEMENT [IN] IS EXCITED WITH GaN-BASED COMPOUND SEMICONDUCTOR LASER ELEMENT.**

Verification for the requested correction is indicated on the original Declaration and Power of Attorney filed September 11, 2000.

Respectfully submitted,

Darryl Mexic  
Registration No. 23,063

SUGHRUE, MION, ZINN,  
MACPEAK & SEAS, PLLC  
2100 Pennsylvania Avenue, N.W.  
Washington, D.C. 20037-3213  
Telephone: (202) 293-7060  
Facsimile: (202) 293-7860  
Date: November 8, 2000

RECEIVED  
JAN - 9 2001  
TECHNOLOGY CENTER 2800

Off. Coe  
#5 CFR  
1/10/01



UNITED STATES PATENT AND TRADEMARK OFFICE

COMMISSIONER FOR PATENTS  
UNITED STATES PATENT AND TRADEMARK OFFICE  
WASHINGTON, D.C. 20231  
[www.uspto.gov](http://www.uspto.gov)

APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTY.DOCKET.NO	DRAWINGS	TOT CLAIMS	IND CLAIMS
09/659,456	09/11/2000	2874	1302	Q58705	8	54	2

Sughrue Mion Zinn MacPeak & Seas PLLC  
2100 Pennsylvania Avenue NW  
Washington, DC 20037-3202



**FILING RECEIPT**



\*OC00000005515022\*

Date Mailed: 10/30/2000

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the PTO processes the reply to the Notice, the PTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

**Applicant(s)**

Yoji Okazaki, Kaisei-machi, JAPAN;  
Toshiaki Fukunaga, Kaisei-machi, JAPAN;

**Continuing Data as Claimed by Applicant**

**Foreign Applications**

JAPAN 257529/1999 09/10/1999

If Required, Foreign Filing License Granted 10/28/2000

**Title**

Laser apparatus in which GaN-based compound surface-emitting semiconductor element[<sup>IS</sup>]  
excited with GaN-based compound semiconductor laser element

**Preliminary Class**

372

**RECEIVED**  
JAN - 9 2001  
TECHNOLOGY CENTER 2800

Data entry by : DAVENPORT, BOBBIE

Team : OIPE

Date: 10/30/2000

